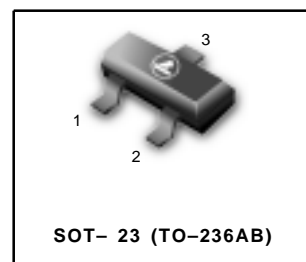


Low Noise Transistor

PNP Silicon

- We declare that the material of product compliance with RoHS requirements.

LMBT5087LT1G

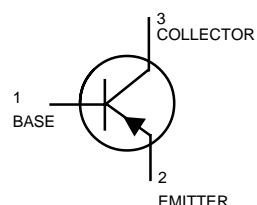


ORDERING INFORMATION

Device	Marking	Shipping
LMBT5087LT1G	2Q	3000/Tape & Reel
LMBT5087LT3G	2Q	10000/Tape & Reel

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	- 50	Vdc
Collector–Base Voltage	V_{CBO}	- 50	Vdc
Emitter–Base Voltage	V_{EBO}	- 3.0	Vdc
Collector Current — Continuous	I_C	- 50	mAdc



DEVICE MARKING

LMBT5087LT1G =2Q

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation RF-5 Board (1) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55to+150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
----------------	--------	-----	-----	------

OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ($I_C = -1.0\text{ mAdc}, I_E = 0$)	$V_{(BR)CEO}$	- 50	—	Vdc
Collector–Base Breakdown Voltage ($I_C = -100\ \mu\text{Adc}, I_E = 0$)	$V_{(BR)CBO}$	- 50	—	Vdc
Collector Cutoff Current ($V_{CB} = -10\text{ Vdc}, I_E = 0$) ($V_{CB} = -35\text{ Vdc}, I_E = 0$)	I_{CBO}	—	-10 -50	n Adc

1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

LMBT5087LT1G
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
DC CHARACTERISTICS				
DC Current Gain ($I_C = -100\mu\text{Adc}$, $V_{CE} = -5.0\text{ Vdc}$)	h_{FE}	250	800	—
($I_C = -1.0\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$)		250	—	
($I_C = -10\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$)		250	—	
Collector–Emitter Saturation Voltage ($I_C = -10\text{ mAdc}$, $I_B = -1.0\text{ mAdc}$)	$V_{CE(sat)}$	—	-0.3	Vdc
Base–Emitter Saturation Voltage ($I_C = -10\text{ mAdc}$, $I_B = -1.0\text{ mAdc}$)	$V_{BE(sat)}$	—	-0.85	Vdc

SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ($I_C = -500\mu\text{Adc}$, $V_{CE} = -5.0\text{ Vdc}$, $f = 20\text{ MHz}$)	f_T	40	—	MHz
Output Capacitance ($V_{CB} = -5.0\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	C_{obo}	—	4.0	pF
Small–Signal Current Gain ($I_C = -1.0\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$, $f = 1.0\text{ kHz}$)	h_{fe}	250	900	—
Noise Figure ($I_C = -20\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$, $R_S = 10\text{ k}\Omega$, $f = 1.0\text{ kHz}$)	NF	—	2.0	dB
($I_C = -100\mu\text{Adc}$, $V_{CE} = -5.0\text{ Vdc}$, $R_S = 3.0\text{ k}\Omega$, $f = 1.0\text{ kHz}$)		—	2.0	

LMBT5087LT1G

TYPICAL NOISE CHARACTERISTICS

($V_{CE} = -5.0$ Vdc, $T_A = 25^\circ\text{C}$)

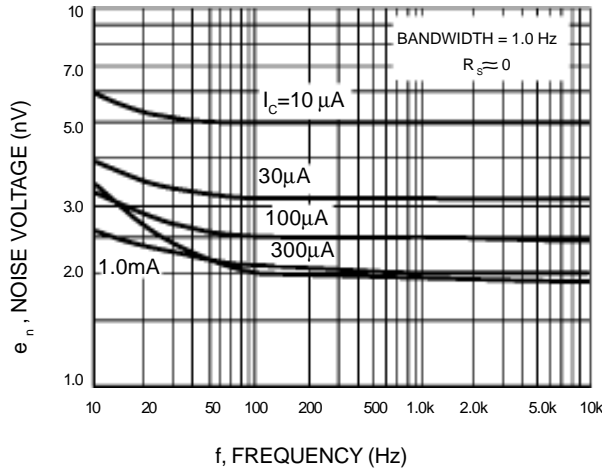


Figure 1. Noise Voltage

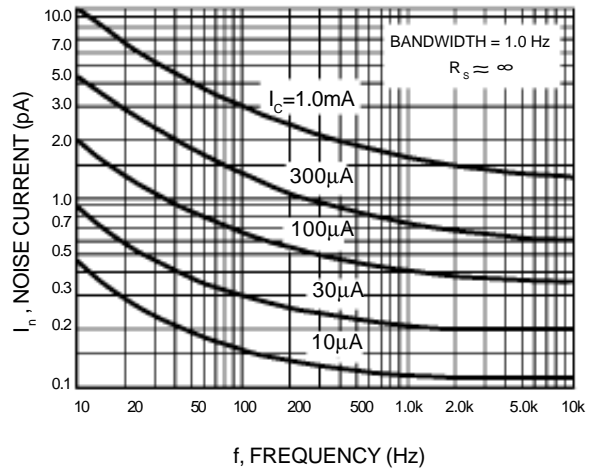


Figure 2. Noise Current

NOISE FIGURE CONTOURS

($V_{CE} = -5.0$ Vdc, $T_A = 25^\circ\text{C}$)

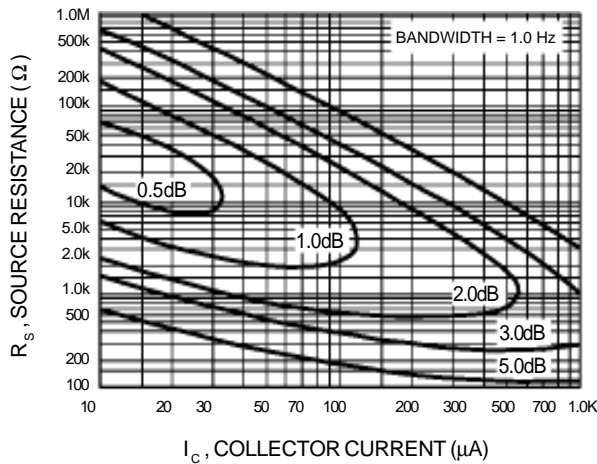


Figure 3. Narrow Band, 100 Hz

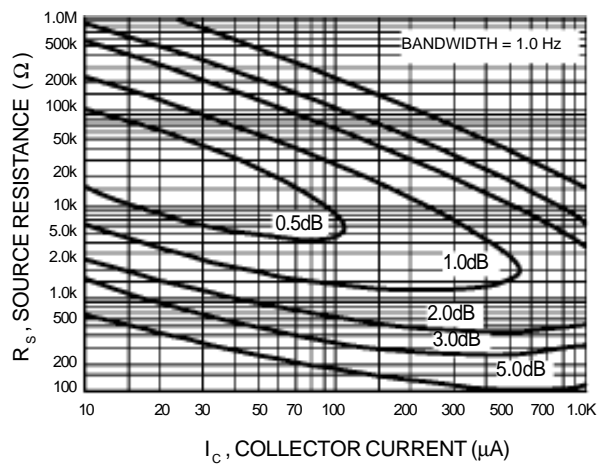


Figure 4. Narrow Band, 1.0 kHz

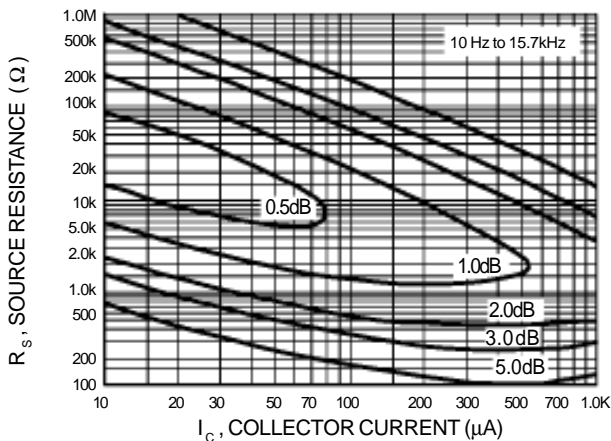


Figure 5. Wideband

Noise Figure is Defined as:

$$NF = 20 \log_{10} \left(\frac{e_n^2 + 4KTR_s + I_n^2 R_s^2}{4KTR_s} \right)^{1/2}$$

e_n = Noise Voltage of the Transistor referred to the input. (Figure 3)

I_n = Noise Current of the Transistor referred to the input. (Figure 4)

K = Boltzman's Constant (1.38×10^{-23} J/°K)

T = Temperature of the Source Resistance (°K)

R_s = Source Resistance (Ω)

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TYPICAL STATIC CHARACTERISTICS

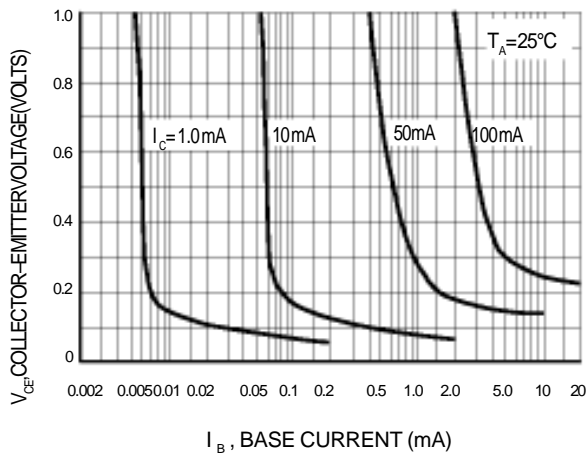


Figure 6. Collector Saturation Region

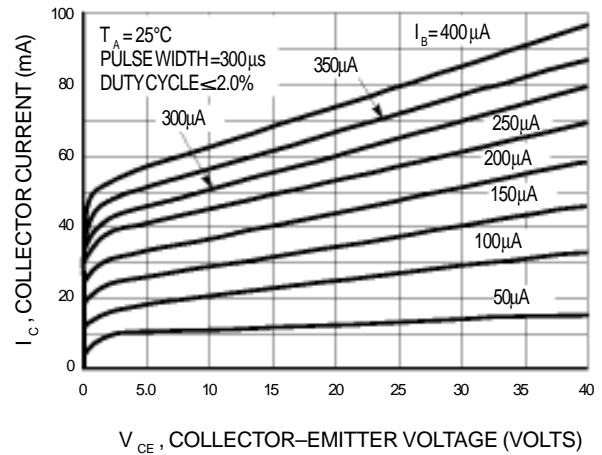


Figure 7. Collector Characteristics

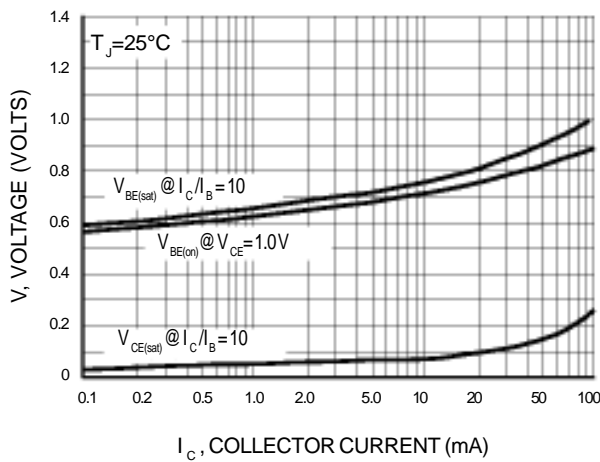


Figure 10. "On" Voltages

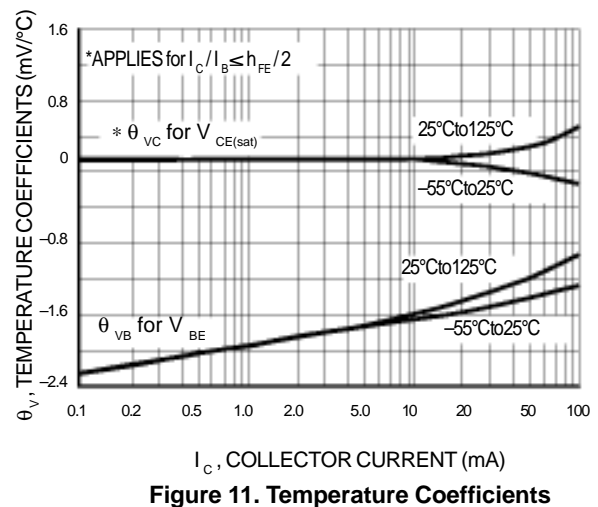


Figure 11. Temperature Coefficients

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TYPICAL DYNAMIC CHARACTERISTICS

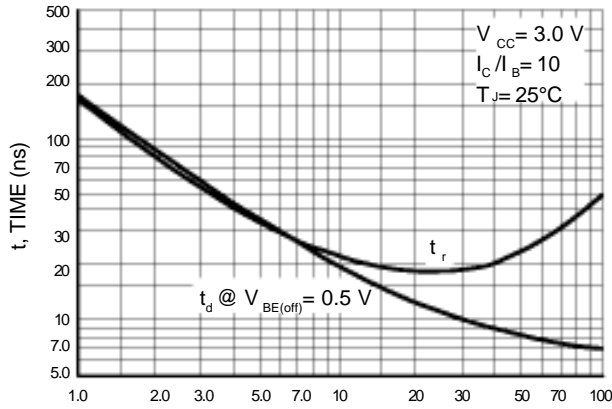


Figure 10. Turn-On Time

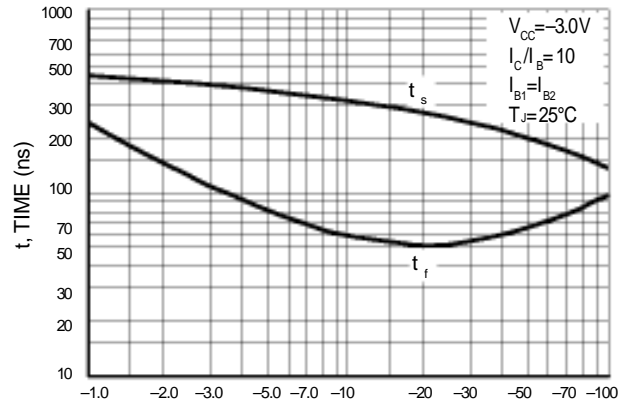


Figure 11. Turn-Off Time

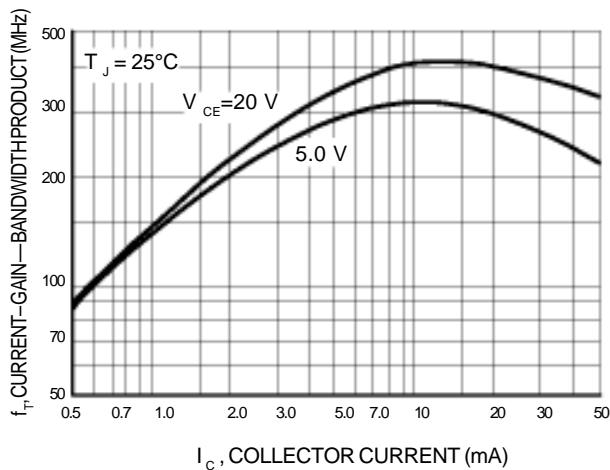


Figure 12. Current-Gain — Bandwidth Product

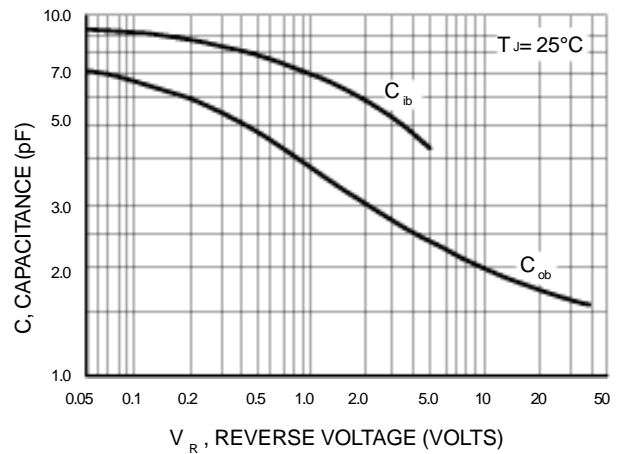


Figure 13. Capacitance

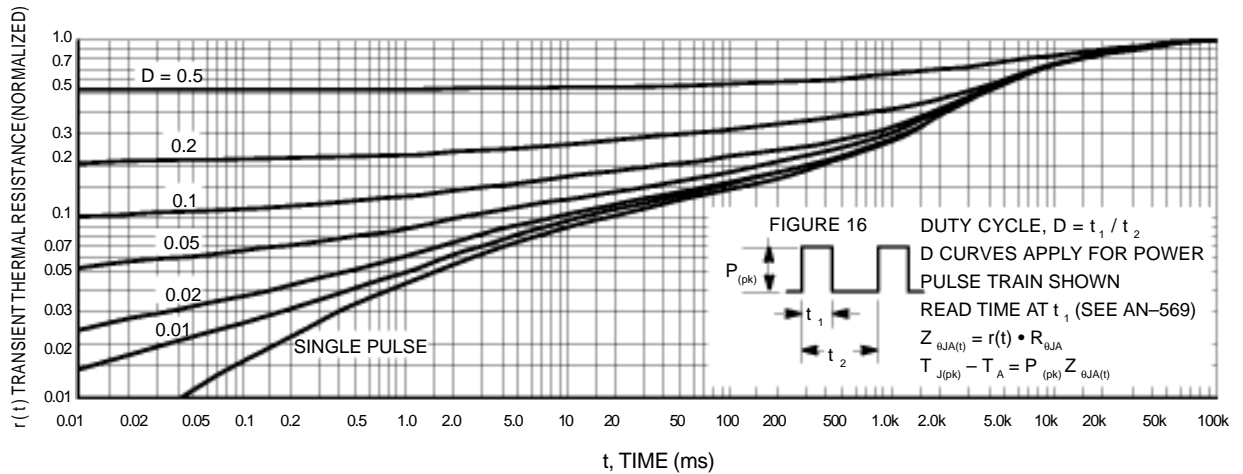


Figure 14. Thermal Response

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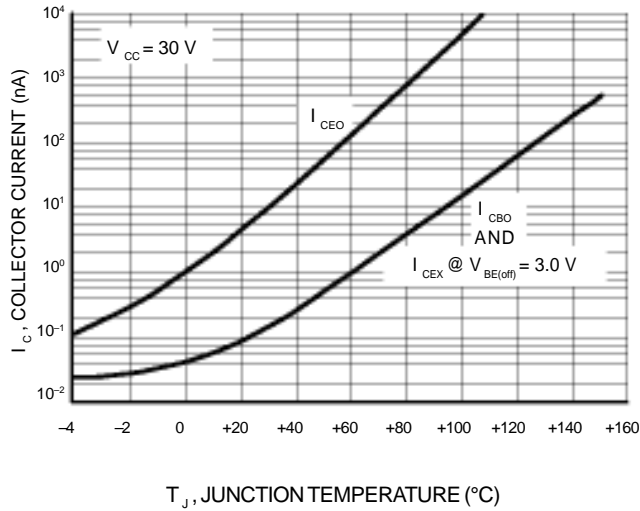


Figure 15. Typical Collector Leakage Current

DESIGN NOTE: USE OF THERMAL RESPONSE DATA

A train of periodical power pulses can be represented by the model as shown in Figure 16. Using the model and the device thermal response the normalized effective transient thermal resistance of Figure 14 was calculated for various duty cycles.

To find $Z_{\theta JA(t)}$, multiply the value obtained from Figure 14 by the steady state value $R_{\theta JA}$.

Example:

Dissipating 2.0 watts peak under the following conditions:

$t_1 = 1.0$ ms, $t_2 = 5.0$ ms. ($D = 0.2$)

Using Figure 16 at a pulse width of 1.0 ms and $D = 0.2$, the reading of $r(t)$ is 0.22.

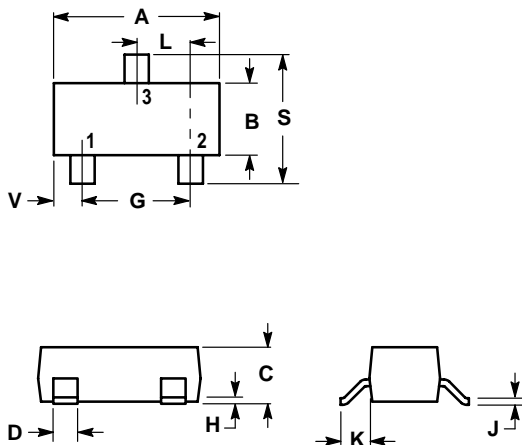
The peak rise in junction temperature is therefore

$$\Delta T = r(t) \times P_{(pk)} \times R_{\theta JA} = 0.22 \times 2.0 \times 200 = 88^\circ\text{C}.$$

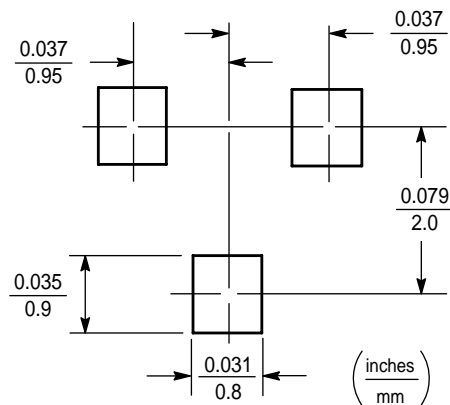
For more information, see AN-569.

LMBT5087LT1G
SOT-23
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60



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